Selective ion sieving through arrays of sub-nanometer nanopores in chemically tunable 2D carbon membranes†

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Two-dimensional (2D) membranes featuring arrays of sub-nanometer pores have applications in purification, solvent separation and water desalination. Compared to channels in bulk membranes, 2D nanopores have lower resistance to transmembrane transport, leading to faster passage of ions. However, the formation of nanopores in 2D membranes requires expensive post-treatment using plasma or ion bombardment. Here, we study bottom-up synthesized porous carbon nanomembranes (CNMs) of biphenyl thiol (BPT) precursors. Sub-nanometer pores arise intrinsically during the BPT-CNM synthesis with a density of 2 ± 1 pore per 100 nm². We employ BPT-CNM based pore arrays as efficient ion sieving channels, and demonstrate selectivity of the membrane towards ion transport when exposed to a range of concentration gradients of KCl, CsCl and MgCl₂. The selectivity of the membrane towards K⁺ over Cl⁻ ions is found be 16.6 mV at a 10 : 1 concentration ratio, which amounts to ~30% efficiency relative to the Nernst potential for complete ion rejection. The pore arrays in the BPT-CNM show similar transport and selectivity properties to graphene and carbon nanotubes, whilst the fabrication method via self-assembly offers a facile means to control the chemical and physical properties of the membrane, such as surface charge, chemical nature and pore density. CNMs synthesized from self-assembled monolayers open the way towards the rational design of 2D membranes for selective ion sieving.

Introduction

In ultrafiltration, solvent separation, desalination and reverse osmosis, 2D materials represent an ultimately thin barrier for passing solutes and are therefore prospected to compete with conventional membranes in energy efficiency.1–6 The unique filtration properties of nanopores can best be exploited when pore dimensions are brought down to the size of single molecules and ions, so that the pores reject the passage of ions and molecules based on size exclusion and electrostatic repulsion. However, the reproducible formation of sub-nanometer pores in 2D membranes with high pore density remains a challenge.7,8 Porous 2D membranes are commonly fabricated via top-down methods: starting with a continuous 2D layer, followed by the formation of pores by ion bombardment, electron bombardment or reactive plasma exposure.9 As evident from a recent review focusing on top-down approaches to fabricate porous 2D membranes, pore densities of 1–10 pores per 100 nm² were the highest obtained.10 To achieve these densities, as well as effective control over the pore sizes, the post-modification of a pristine 2D membrane requires highly advanced facilities for controlled electron or ion exposure.

A more versatile route is the bottom-up synthesis of porous 2D membranes from precursor molecules.11,12 A straightforward-forward advantage of the bottom-up approach is its scalability without the need for post-modification steps, high-end lithographic facilities or cleanrooms. In bottom-up fabrication, pore formation is intrinsic to the membrane synthesis, arising from stacking defects during molecular self-assembly. Another advantage lies in the wide variety of precursor molecules that can be incorporated in the membrane. The choice of precursor molecule gives control over pore size and density, as well as over the chemical composition of the membrane – for instance to tune the hydrophobicity of the membrane or to induce specific interactions between the membrane and solute ions.
or molecules. In particular, carbon nanomembranes (CNMs), formed via self-assembly of aromatic thiol-precursor molecules, have been shown to display pore densities in the range required for applications such as desalination by reverse osmosis and as separation membranes. Beside the pore density, which determines through-put, a key factor in the efficiency of filtration is the pore size distribution in a 2D membrane, with smaller pores yielding higher selectivity in trans-membrane transport. Previous studies have revealed that the pore size in CNMs is determined by the size and structure of the precursor molecules. Precursors of decreasing molecular size yield membranes with decreasing pore diameter, as well as a thinner membrane. In the current work, we use the precursor molecule 1,1′-biphenyl-4-thiol (BPT); one of the smallest precursors that still forms a stable CNM, with a near-2D thickness of ~0.9 nm and strong enough to be suspended over micrometers.

The BPT-CNM is therefore an ideal candidate for ion filtration applications. However, the porosity of the BPT-CNM has not been characterized to date, due to the difficulty of imaging sub-nanometer features in 2D membranes. Whereas nanopores of sub-nanometer sizes have been resolved in crystalline graphene layers produced via pyrolysis of CNMs, the disordered nature of the CNMs complicates the visualization of sub-nanometer pores. The smallest CNM in which porosity has been resolved was made from \([1\text{,}1\text{,}4\text{,}1\text{]}\)-terphenyl-4-thiol (TPT) precursors, for which pore dimensions of 0.7 ± 0.1 nm have recently been reported.

Here, we determine the pore density in the BPT-CNM for the first time, using a combination of high-resolution transmission electron microscopy (HR-TEM) imaging and ionic conductance measurements. In an earlier study, TEM has been used to resolve BPT-CNM membrane based pores of several nanometers in diameter, which were induced by ion beam exposure, and did not reveal any pores with smaller sizes. On the other hand, we show here that pores are in fact present in the pristine BPT-CNM, as evident from transmembrane ion conductivity through the BPT-CNM membrane. The number and size of pores in a well-defined area of the membrane are determined using the ion flow through the membrane. In this way, the porosity of each membrane sample can be determined in operando. Next, we demonstrate the use of the BPT-CNM as ion-sieving membranes. In saline solution, one ion type is preferentially transmitted through the sub-nanometer pores in the BPT-CNM while counter-ions are rejected. This ion selectivity is essential to applications in desalination, energy generation and energy storage. Ion selectivity in transport through the membrane pores is based on electrostatic repulsion by charges present on the membrane surface, as shown by a range of studies probing charge-selective ion transport through nanoporous 2D membranes. In the BPT-CNM, charged groups include residual sulfide groups. Moreover, ion selectivity in 2D nanoporous membranes has been observed even in chemically neutral membranes, including graphene and molybdenum sulfide. It has therefore been suggested that in aqueous environment, adsorbed oxygen species add a negative surface charge to 2D membranes irrespective of the chemical composition of the membrane.

### Results and discussion

To estimate the pore density in the BPT-CNM, we expressed the measured ionic conductance in terms of the length and diameter of the membrane-based pores, according to a model developed for the description of conductance through nanopores in SiN membranes, assuming continuous charge flow:

\[
G = \sigma_e \left( \frac{4l}{\pi d^2} + \frac{1}{d} \right)^{-1}
\]

Herein, \(d\) and \(l\) describe the average diameter and length of a single pore through which the conductance \(G\) is measured. The bulk electrolyte conductivity \(\sigma_e\), with the units Siemens per meter (S m\(^{-1}\)), is determined by the ionic strength of the solution. We adjusted this model to describe not the conductance of a single pore, but of an array of pores in a suspended CNM, defining the number of sub-nanometer pores in the exposed membrane area in terms of the recorded conductance \((G_{\text{meas}})\) of the carbon nanomembrane:

\[
n_A = \frac{G_{\text{meas}}}{\sigma_e} \cdot \left( \frac{4l}{\pi d^2} + \frac{1}{d} \right)
\]

Here, \(n_A\) is the number of pores in the suspended membrane area \(A\) and \(d\) the average pore diameter.

In order to expose a well-defined BPT-CNM area, the CNM was deposited on a SiN chip featuring an aperture that was sculpted in the SiN membrane using the focused beam of an electron microscope. The diameter of the nano-aperture ranged between 20 and 80 nm. Fig. 1a depicts the deposition method: the CNM was synthesized by self-assembly of precursor molecules on a gold film on a mica support (Fig. 1a, step 1). Subsequent cross-linking by electron irradiation (step 2) resulted in a covalent 2D network. The membrane was then transferred onto the SiN aperture-chip using PMMA-assisted transfer, as presented in Fig. 1a and in detail in the Experimental section. Fig. 1b shows a SiN aperture prior to membrane deposition imaged by TEM after sculpting the aperture. The aperture chip was imaged again after deposition of the CNM, using aberration-corrected high-resolution (HR) TEM. Fig. 1c shows one membrane imaged by HR-TEM, revealing an integral membrane with no visible pores. From the integrity of the membrane in the electron images, we can assume that the size of the pores in BPT-CNM does not exceed 1 nm. This is a rather conservative estimate, given the instrumental resolution that can be attained in principle by aberration-corrected HR-TEM at the 80 kV operating voltage is 0.18 nm. However, we take into account several factors limiting the resolution attained in TEM imaging: firstly, a high defocus was required to gain sufficient contrast from the amorphous BPT-CNM membrane, which reduced the resolution. Secondly, the applicable electron dose for imaging is limited because the BPT-CNM was observed to deteriorate significantly at too high
electron doses, with holes forming during imaging at dose rates >10^5 e^- nm^-2 s^-1.

To collect information about the pores in the BPT-CNM, trans-membrane ionic conductance measurements were performed. The ionic conductance through the CNM exposed by the SiN aperture was determined from current-voltage curves recorded in the flow cell, such as shown in the inset of Fig. 1d. The conductance of the membrane can in principle be simply determined using Ohm’s law. However, for ion transport through 2D nanopores, deviations from ohmic behavior have been reported in literature23–25 and observed in our measurements, too. Two types of non-linear IV-characteristics occurred: rectification and activation. Rectification is a difference in conductance in the positive voltage range respective to the negative voltage range. Activation is the superlinear increase of conductance with increasing voltage across the pore. Both effects have been shown to be related to dehydration phenomena in the confinement of 2D nanochannels. In this work, our sole interest lies with the conductance of the pore towards hydrated ions. Therefore, the conductance was determined applying Ohm’s law in the region close to zero bias, where the conductance of hydrated ions is most closely approximated.

The ionic conductance through eleven CNM-coated SiN apertures was measured, both before and after CNM deposition. The data are presented in Fig. 2a. Typically, deposition of the membrane (blue) led to a 30% drop in the measured conductance relative to the bare SiN aperture (red). The conductance of the CNM samples with different free-standing areas falls faithfully on the same line, reflecting the homogeneity of the membrane. The linearity of the conductance versus membrane area furthermore confirms that the conductance stems from the ionic current passing through the membrane, without significant contributions from leak currents.

The membrane conductance in 1 M KCl was used to make a quantitative statement about the porosity of the BPT-CNM. From the linear regression of the conductance value in Fig. 2a (blue data points), the average membrane conductance (G_{CNM}) per area was found to be G_{CNM} = 4.8 \times 10^{-5} \text{ S} \text{m}^{-2}. Based on this value, we estimated the porosity of the BPT-CNM according to eqn (2). Note that the contribution to the resistance from the SiN aperture is not negligible and was accounted for by subtracting the bare aperture conductance (red) from the CNM conductance (blue) – see ESI S1.†

Eqn (2) contains two unknown parameters: \( n \), the number of pores contributing to ion transport and \( (d) \), the average diameter of the pores. The solution, thus, is a set of possible combinations of \( n \) and \( (d) \), shown in Fig. 2b. To find the actual values for both \( n \) and \( (d) \), we considered first, a lower limit to the size of the pores contributing to the ionic current, which is given by the radius of the smallest charge carrier. Of the main charge carriers in KCl electrolyte, K⁺ is the smallest, with a hydrated diameter of 0.56 nm.26 As ions are expected to be excluded by pores smaller than the hydrated ion diameter, K⁺ sets the lower limit to the pore diameter at \( d_{\text{min}} = 0.56 \text{ nm} \). The upper limit to the pore diameter was defined considering that the membrane imaged by HR-TEM appears free of pores larger than 1 nm.

We concluded that the diameter of the pores contributing to the ionic current falls in the range of 0.56 < \( (d) < 1 \text{ nm} \) (indicated by the yellow region in Fig. 2b). It follows that the pore density of the BPT-CNM lies between 1 and 2.7 pores per 100 nm². The exposed membrane area ranged from 20 to

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**Fig. 1** Fabrication of suspended biphenyl thiol carbon nanomembrane (BPT-CNM) chips. (a) Schematic procedure used to fabricate free-standing BPT-CNM, starting with the formation of the BPT-SAM on the surface of gold on mica (1). Subsequent electron irradiation cross-links the BPT-SAM to form the BPT-CNM (2). A protective layer of PMMA is spin-coated onto the stack (3). The PMMA/CNM/gold stack is exfoliated from the mica support (4) and suspended on water, after which it is transferred to the surface of a KI/I₂ solution that etches away the gold film (5). Through a sequence of washing steps (see Experimental section) the KI/I₂ solution is replaced by ultrapure water from which the stack is scooped up onto the SiN/SiO₂ wafer (6). After drying, PMMA is removed in acetone (7), which is exchanged for supercritical CO₂ to prevent left-over contaminations on the final membrane. (b) A 60 nm diameter aperture in SiN after drilling by the focused beam of a TEM. (c) The aperture from (b) after deposition of PMMA (8). (d) Typical IV curve measured on a CNM suspended over a SiN aperture in 1 M KCl solution. Inset: The suspended BPT-CNM imaged by HR-TEM.
80 nm diameter, so that between 10 and 200 pores partook as conductive channels.

Next, the membrane potential across the BPT-CNM was determined following Nernst-Plank membrane theory. The membrane potential is the potential difference between the two sides of the membrane in the presence of an electrolyte concentration gradient. In the presence of such a concentration gradient, diffusion drives ions to the lower concentration side of the membrane. If both cations and anions pass through the membrane at equal rates, no potential would arise. However, in the case of an ion selective membrane, preferential transport of one ion type over the counter-ion results in a net ionic current. The membrane potential is the voltage associated with this current.

Current–voltage characteristics measured in the presence of varying concentration ratios are shown in Fig. 2c. The inset shows the IV-curve measured at a 1 : 10 concentration ratio in close-up around the origin. To find the membrane potential, we determined the voltage measured at zero current (i.e., the intersection with the x-axis of the linear fit through the data points). This is the potential at which the selective ionic current was exactly compensated, called the reversal potential. The reversal potential is of equal magnitude (although of opposite sign) to the membrane potential. The membrane potential is thus 32% of the Nernst potential.

For the BPT-CNM, a higher value than 32% of the theoretical Nernst potential may have been expected, since ion selectivity should be very efficient in pores that approach the size of hydrated ions – as is the case in the BPT-CNM. This discrepancy can be understood considering that the Nernst-Planck membrane theory was developed for conventional, 3D ion selective membranes. In 3D porous membranes, ion selectivity arises due to a bulk membrane phase that is distinct from the adjacent electrolyte phases. In 2D membranes, on the other hand, a bulk membrane phase is ill-defined because of the near-zero length of pore channels. The use of 2D membrane thus allows easier ion transport because of the minimal barrier separating the bulk electrolyte phases on either side of the membrane, resulting in a membrane potential of only 32% of the expected membrane potential for 3D membranes. From these results it is...
clear that the description of ion selective transport in 2D membranes requires an extension of Nernst-Planck theory to accurately describe measured membrane potentials.

The positive membrane voltage reveals the selectivity towards cations in KCl electrolyte. Conversely, repeated measurement of the membrane potential in MgCl2 and CsCl solutions revealed the dependence of selectivity to the valency of the electrolyte salt used, as the membrane potential changes sign in the case of divalent MgCl2 (Fig. 2d). This observation may be attributed to charge inversion, a phenomenon in which divalent cations overcompensate the negative charge on a surface, effectively changing the sign of the surface charge. An alternative explanation is that the electrostatic charges causing selectivity are screened more efficiently in a divalent salt solution – that has a three times higher ionic strength than a monovalent salt solution of the same concentration. When charges on the pore edge are efficiently screened, the factor determining selective transport is the ion mobility. The Cl− ion, with a higher diffusion coefficient than the Mg2+ ion, becomes the main charge carrier in MgCl2 electrolyte. This results in an opposite membrane potential to KCl and CsCl, where the cations were the main charge carriers. The selectivity of the membrane is thus responsive to the electrolyte composition and valency.

More insight in the specific interactions between membrane and electrolyte can be obtained by changing the chemical composition of the membrane. As the chemical synthesis of the CNM allows control over the membrane chemistry, such as the addition of specific charged groups, this kind of membranes hold the prospect of increasing our understanding into the nature of membrane-electrolyte interactions, and result in new selective transport phenomena.

To conclude, the bottom-up synthesized carbon nanomembranes provide a scalable and reproducible approach to obtain high density sub-nanometer pores in a 2D membrane. Integrating the BPT-CNMs in an ionic conductance measurement flow-cell, we showed that the pores in the BPT-CNMs act as effective ion sieving channels. We were able to determine the density of ion channels in operando, allowing the individual characterization of the porosity in each membrane sample and finding a highly uniform and reproducible pore density. The density of pores contributing to ion transport in the BPT-CNMs was 1–2.7 pores per 100 nm2, comparable with the high-end top-down approaches where pores are induced in post-modification steps involving ion or electron bombardment. The significant deviation of the membrane potential from the Nernst potential, as well as membrane charge inversion in the presence of MgCl2, are typical to transport through 2D membranes. The BPT-CNMs membrane is thus a suitable platform to study the mechanisms underlying ion transport through 2D sub-nanometer pores, more easily obtained than for instance in carbon nanotubes or graphene nanopores produced by lithography. In addition, the possibility of tuning – chemically – the composition of the membrane holds the prospect of rational design of membranes with desired surface properties and chemical functionality.

Experimental

SiN aperture sculpting

SiN windows of 50 × 50 µm2, supported on SiO2 chips, were purchased from Norcada. The SiN/SiO2 chips were cleaned in piranha solution before insertion in the electron microscope (Tecnai T20 operating at 200 kV; Thermo Fischer Scientific, previously FEI). Nano-apertures were sculpted in the SiN window using the focused electron beam. After sculpting, the SiN/SiO2 chips were stored in a sonicated mixture of 50:50 EtOH:H2O (absolute ethanol, >98%, Sigma Aldrich; Milli-Q) for protection against vibrations as well as prevention of clogging the nano-aperture by contaminations, until the moment BPT-CNMs deposition.

BPT-CNMs fabrication

A gold/mica substrate (Georg Albert PVD-Coatings) was cleaned for 1 minute in oxygen plasma (Zepto 115320, Diener). The gold/mica substrate was then immersed in a ~0.1 mM solution of 1,1′-biphenyl-4-thiol (BPT, Sigma Aldrich) in degassed DMF (Sigma Aldrich, 99.9%) for 72 h under dark conditions, during which self-assembled BPT monolayer formed on the gold surface. After the self-assembly, the substrate was taken out and immediately washed three times with DMF followed by three times washing with ethanol (Sigma Aldrich, 99.8%) to remove possible residual BPT molecules that may have adsorbed on top of the monolayer. The samples were then dried under nitrogen flow (5.0, Linde) and transferred to a high vacuum chamber (1 × 10−8 mbar) for electron exposure. An electron beam at 100 eV and 50 mC cm−2 electron dose induced molecular cross-linking of the BPT-SAM molecules on the gold surfaces to form a stable membrane. The quality of the formed BPT-SAMS and BPT-CNMs was monitored using X-ray photoelectron spectroscopy (XPS, Fig. S3 and S4†). XPS was carried out on an ultra-high vacuum Multiprobe UHV system (base pressure 1 × 10−10 mbar) from Scienta Omicron, using a monochromatic X-ray source (Al Kα) and an electron analyzer (Argus) with a spectral resolution of 0.6 eV.

Transfer of the CNMs onto SiN/SiO2 chips

The transfer procedure was conducted as described elsewhere. A PMMA layer (100 nm, 50 kDa, All-Resist, AR-P 671.04) was spin coated onto the CNM on gold/mica and hardened for 10 min at 90 °C. Subsequently, a thicker layer of PMMA (200 nm, 950 kDa, All-Resist, AR-P 679.04) was spin coated on top of the first one and hardened for 10 min at 90 °C. The PMMA-CNMs-Au sandwich was cleaved from the mica substrate by repeatedly and gradually dipping the sample into water. An etching solution (I2/KI/H2O, 1:4:10 by mass) was used to dissolve the gold layer at room temperature. Molecular I2, which adheres to the bottom side of the CNM was removed by floating the CNM-PMMA layer on Na2S2O3 (0.1 wt%) solution for 5 min. The CNM-PMMA layer was washed 6 times with ultrapure water before transfer to the target substrate, followed by baking at 90 °C for 1 h. The PMMA layer was removed by dipping the sample into acetone (Sigma Aldrich, 99.9%).
To clean the free-standing areas from PMMA impurities, and to avoid rupture of the free-standing CNMs caused by the drying of acetone, acetone was exchanged with liquid CO$_2$ in a critical point dryer (Autosamdri 815, Tousimis) and the CO$_2$ was removed by forming a super fluid medium.

**HR-TEM imaging**

Aberration-corrected high-resolution TEM (AC-HRTEM) on the BPT-CNMs after deposition on the Si$_3$N$_4$ aperture was performed using an FEI Titan 80–300 microscope with third-order aberration correction by a hexapole image corrector. The TEM acceleration voltage was set to 80 kV in order to minimize electron beam-induced damage. The AC-HRTEM images of BPT-CNMs were recorded using a Gatan Ultrascan 1000XP CCD camera with frame sizes of 2048 × 2048 pixels, at electron dose rates of the order of 10$^5$ e$^-$ nm$^{-2}$ s$^{-1}$.

**Ionic conductance measurements**

Current–voltage traces were recorded in a custom fabricated flow cell designed to clamp the SiN/SiO$_2$ chip between two electrolyte reservoirs of approximately 150 µL. After insertion of the chip into the flow-cell, both reservoirs were flushed with a sonicated mixture of ethanol in ultrapure water (50 : 50) to prevent air bubbles from sticking to the membrane surface. Subsequently, ultrapure water (Milli-Q) was flushed three times, followed by two times flushing electrolyte solution. When the electrolyte was changed during measurements of reversal potential, the reservoir was flushed twice with the new concentration electrolyte.

For the preparation of fresh Ag/AgCl electrodes, silver wire (Alfa Aesar, 99.999% percent purity) was cut to pieces ~2 cm pieces. The tip of the cut piece was immersed in bleach for at least 30 minutes. After formation of a AgCl layer, the electrode tip was rinsed with ultrapure water and used the same day. The flow cell was placed in a Faraday cage and the two compartments of the flow cell were connected to an Axopatch 200B Patch Clamp setup, through freshly prepared Ag/AgCl electrodes. Current–voltage traces were recorded and analyzed using pCLAMP software.

**Conflicts of interest**

There are no conflicts of interest to declare.

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**References**


